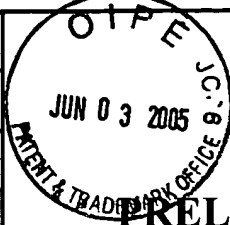


First Named Inventor	Leonard Forbes	 <p><b>PRELIMINARY AMENDMENT</b></p>
Serial No.	10/808,059	
Filing Date	March 24, 2004	
Group Art Unit	2814	
Examiner Name	M. Pizarro Crespo	
Confirmation No.	4221	
Attorney Docket No.	400.285US01	
<p>Title: NROM MEMORY DEVICE WITH HIGH-PERMITTIVITY GATE DIELECTRIC FORMED BY THE LOW TEMPERATURE OXIDIZATION OF METALS</p>		

Commissioner for Patents  
M.S. Amendment  
P.O. Box 1450  
Alexandria, VA 22313-1450

Prior to initial review, please amend the above-identified application as follows to correct a typographical error in the application filing:

**PRELIMINARY AMENDMENT**

**PAGE 3**

Serial No. 10/808;059

Attorney Docket No. 400.285US01

Title: NROM MEMORY DEVICE WITH HIGH-PERMITTIVITY GATE DIELECTRIC FORMED BY THE  
LOW TEMPERATURE OXIDIZATION OF METALS

---

If the Examiner has any questions or concerns regarding this application, please contact the undersigned at (612) 312-2211. No new matter has been added and Applicant believes no additional fee is required by this Preliminary Amendment.

Respectfully submitted,

Date: \_\_\_\_\_

5/31/05

Kenneth W. Bolvin

Kenneth W. Bolvin

Reg. No. 34,125

Attorneys for Applicant  
Leffert Jay & Polglaze  
P.O. Box 581009  
Minneapolis, MN 55458-1009  
T 612 312-2200  
F 612 312-2250